1 Electrical ratings

Table 2.	Absolute n	naximum	ratings
	ADSUILLE	IIaAIIIIuIII	raunyə

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-base voltage (I _E = 0)	150	V
V _{CEO}	Collector-emitter voltage ($I_B = 0$)	60	V
V _{EBO}	Emitter-base voltage (I _C = 0)	7	V
۱ _C	Collector current	5	А
I _{CM}	Collector peak current (t _P < 5 ms)	10	А
Ι _Β	Base current	1	Α
I _{BM}	Base peak current (t _P < 5 ms)	2	А
P _{tot}	Total dissipation at T _{amb} = 25 °C	1.6	W
T _{stg}	Storage temperature	-65 to 150	°C
Τ _J	Max. operating junction temperature	150	°C

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R _{thj-amb}	Thermal resistance junction-ambient ⁽¹⁾	78	°C/W

1. Device mounted on a p.c.b. area of 1 \mbox{cm}^2



2 Electrical characteristics

($T_{case} = 25 \ ^{\circ}C$ unless otherwise specified)

Table 4.	Electrical characteristics						
Symbol	Parameter	Test co	nditions	Min.	Тур.	Max.	Unit
I _{CBO}	Collector cut-off current $(I_E = 0)$	V _{CB} = 120 V V _{CB} = 120 V	T _c = 100 °C			50 1	nΑ μΑ
I _{EBO}	Emitter cut-off current $(I_{\rm C} = 0)$	V _{EB} = 7 V				10	nA
V _{(BR)CBO}	Collector-base breakdown voltage $(I_E = 0)$	I _C = 100 μA		150			V
V _{(BR)CEO} ⁽¹⁾	Collector-emitter breakdown voltage $(I_B = 0)$	I _C = 10 mA		60			V
V _{(BR)EBO}	Emitter-base breakdown voltage $(I_C = 0)$	l _E = 100 μA		7			v
V _{CE(sat)} ⁽¹⁾	Collector-emitter saturation voltage	$I_{C} = 100 \text{ mA}$ $I_{C} = 1 \text{ A}$ $I_{C} = 2 \text{ A}$ $I_{C} = 5 \text{ A}$	$I_B = 5 \text{ mA}$ $I_B = 50 \text{ mA}$ $I_B = 50 \text{ mA}$ $I_B = 200 \text{ mA}$		10 70 140 320	50 120 250 500	mV mV mV mV
V _{BE(sat)} ⁽¹⁾	Base-emitter saturation voltage	I _C = 4 A	I _B = 200 mA		1	1.15	v
V _{BE(on)} ⁽¹⁾	Base-emitter on voltage	$I_{\rm C} = 4$ A	$V_{CE} = 1 V$		0.89	1	V
h _{FE} ⁽¹⁾	DC current gain	$I_{C} = 10 \text{ mA}$ $I_{C} = 2 \text{ A}$ $I_{C} = 5 \text{ A}$ $I_{C} = 10 \text{ A}$	V _{CE} = 1 V	150 150 90 30	300 270 140 50	350	
f _T	Transition frequency	V _{CE} = 10 V	I _C = 100 mA		130		MHz
C _{CBO}	Collector-base capacitance (I _E = 0)	V _{CB} = 10 V	f = 1 MHz		50		pF
t _{on} t _s t _f	Resistive load Turn-on time Storage time Fall time	$I_{\rm C} = 1 \text{ A}$ $I_{\rm B1} = -I_{\rm B2} = 0.7$			50 1.35 120		ns µs ns

Table 4. Electrical characteristics

1. Pulse duration = 300 $\mu s,$ duty cycle $\leq 1.5\%$



Figure 2.

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Electrical characteristics (curves) 2.1

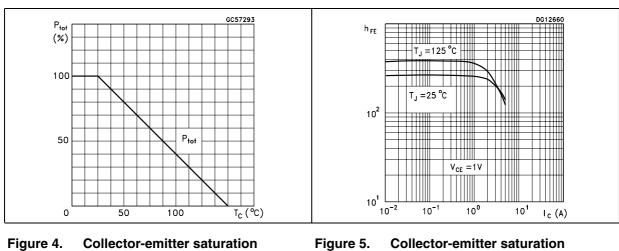


Figure 3.

DC current gain

Figure 4. **Collector-emitter saturation** voltage

Derating curve

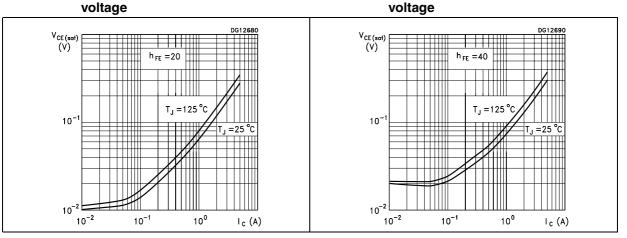
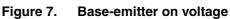
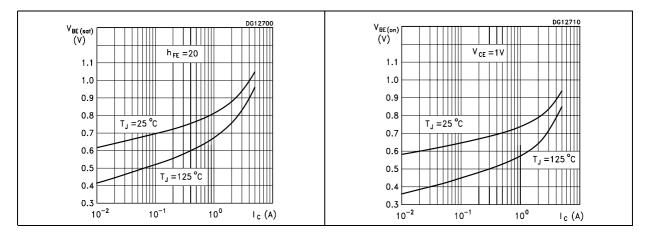


Figure 6. **Base-emitter saturation voltage**





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Figure 8. Resistive load switching time

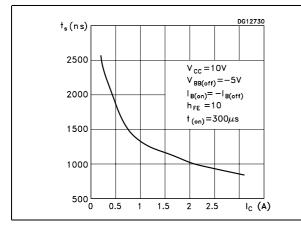


Figure 10. Resistive load switching time

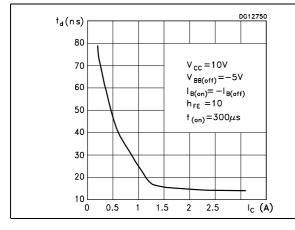
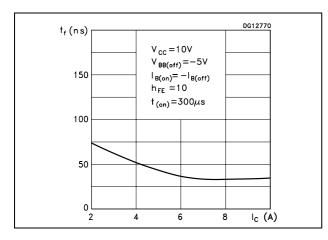


Figure 12. Inductive load switching time



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Figure 9. Resistive load switching time

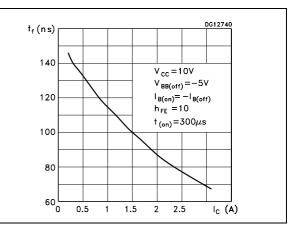
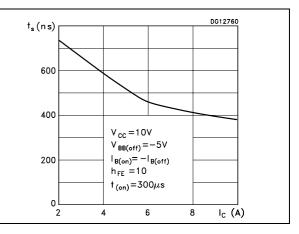


Figure 11. Inductive load switching time



2.2 Test circuit

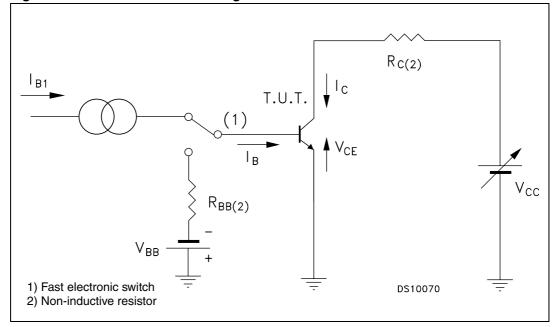


Figure 13. Resistive load switching test circuit

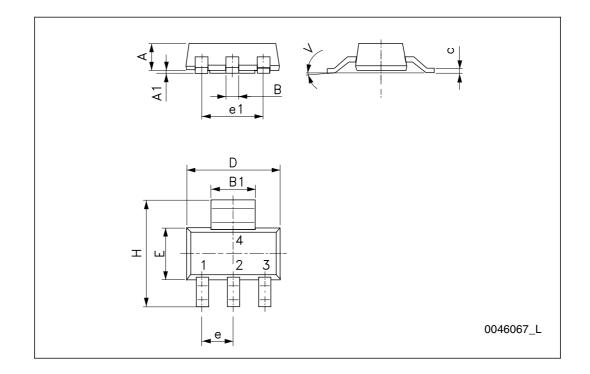


3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and products status are available at: www.st.com. ECOPACK is an ST trademark.



SOT-223 mechanical data			
DIM.		mm.	
	min.	typ	max.
А			1.80
A1	0.02		0.1
В	0.60	0.70	0.85
B1	2.90	3.00	3.15
С	0.24	0.26	0.35
D	6.30	6.50	6.70
е		2.30	
e1		4.60	
E	3.30	3.50	3.70
Н	6.70	7.00	7.30
V			10 ^o



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4 Revision history

Table 5.Document revision history

Date	Revision	Changes
16-Mar-2009	1	First issue



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